

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

- **Single-Supply Operation:**
Input Voltage Range Extends to Ground, and Output Swings to Ground While Sinking Current
- **Input Offset Voltage 300 μV Max at 25°C for LT1014**
- **Offset Voltage Temperature Coefficient 2.5 $\mu\text{V}/^\circ\text{C}$ Max for LT1014**
- **Input Offset Current 1.5 nA Max at 25°C for LT1014**
- **High Gain 1.2 $\text{V}/\mu\text{V}$ Min ($R_L = 2 \text{ k}\Omega$), 0.5 $\text{V}/\mu\text{V}$ Min ($R_L = 600 \Omega$) for LT1014**
- **Low Supply Current 2.2 mA Max at 25°C for LT 1014**
- **Low Peak-to-Peak Noise Voltage 0.55 μV Typ**
- **Low Current Noise 0.07 $\text{pA}/\sqrt{\text{Hz}}$ Typ**

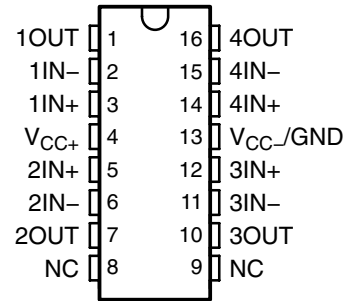
description

The LT1014, LT1014A, and LT1014D are quad precision operational amplifiers with 14-pin industry-standard configuration. They feature low offset-voltage temperature coefficient, high gain, low supply current, and low noise.

The LT1014, LT1014A, and LT1014D can be operated with both dual $\pm 15\text{-V}$ and single 5-V power supplies. The common-mode input voltage range includes ground, and the output voltage can also swing to within a few millivolts of ground. Crossover distortion is eliminated.

The LT1014C and LT1014D are characterized for operation from 0°C to 70°C. The LT1014I and LT1014DI are characterized for operation from -40°C to 105°C. The LT1014M, LT1014AM and LT1014DM are characterized for operation over the full military temperature range of -55°C to 125°C.

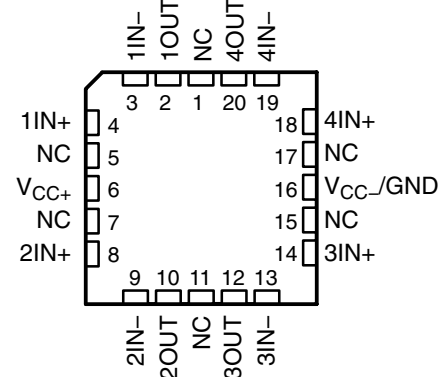
**DW PACKAGE
(TOP VIEW)**



**J OR N PACKAGE
(TOP VIEW)**



**FK PACKAGE
(TOP VIEW)**



NC – No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2009, Texas Instruments Incorporated

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

AVAILABLE OPTIONS[†]

| T _A | V _{IO} max AT 25°C | PACKAGED DEVICES [‡] | | | |
|----------------|--------------------------------|---------------------------------------|------------------------------|----------------------------|----------------------------|
| | | SMALL OUTLINE (DW) [§] | CHIP CARRIER (FK) | CERAMIC DIP (J) | PLASTIC DIP (N) |
| 0°C to 70°C | 300 μV 800 μV | — LT1014DDW | — — | — — | LT1014CN LT1014DN |
| –40°C to 105°C | 300 μV 800 μV | — LT1014DIDW | — — | — — | LT1014IN LT1014DIN |
| –55°C to 125°C | 180 μV 300 μV 800 μV | — — LT1014DMDW | LT1014AMFK LT1014MFK — | LT1014AMJ LT1014MJ — | — LT1014MN LT1014DMN |

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

[‡] Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

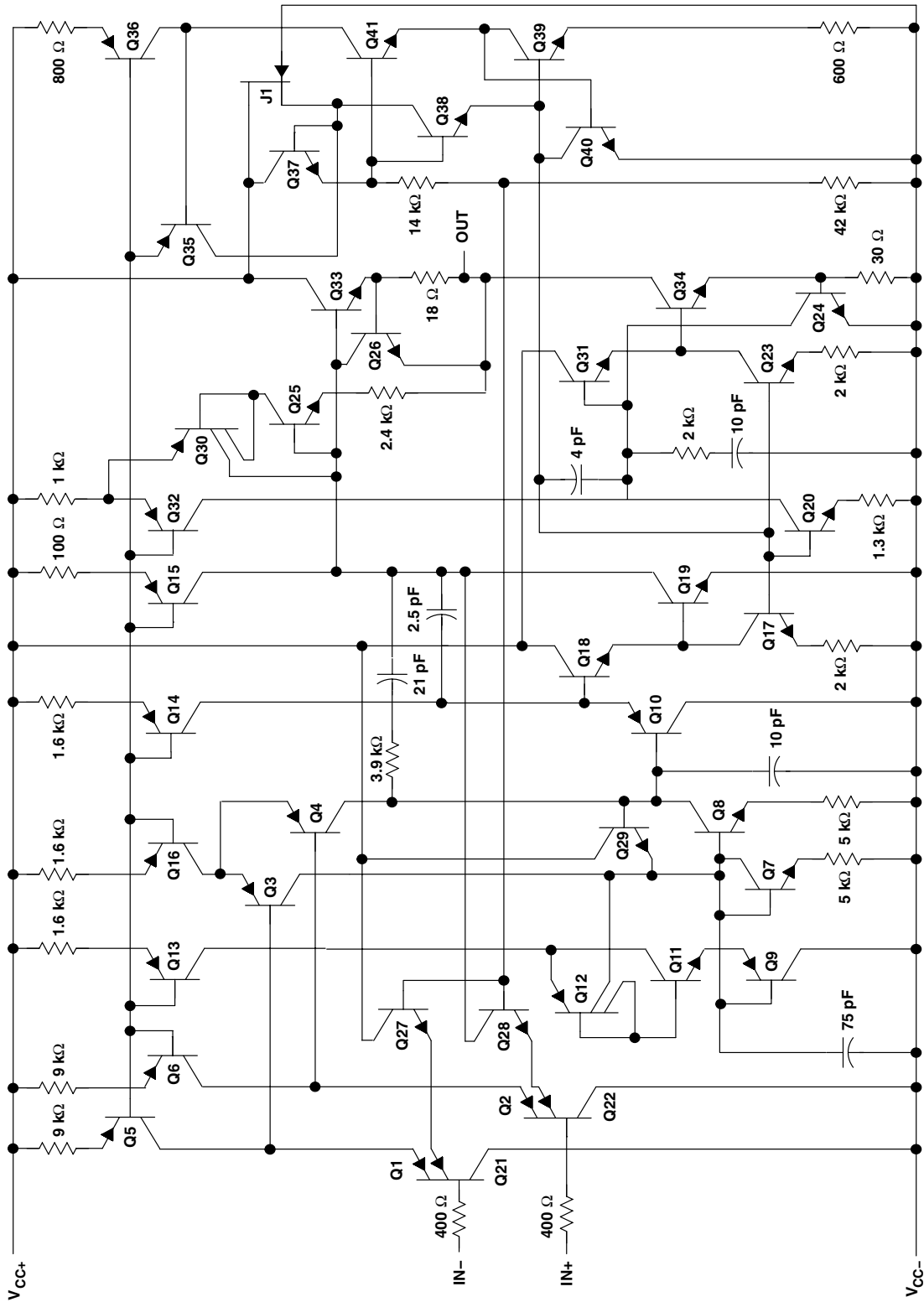
[§] The DW package is available taped and reeled. Add the suffix R to the device type (e.g., LT1014DDWR).



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

schematic (each amplifier)



Component values are nominal.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| | |
|---|--|
| Supply voltage (see Note 1): V_{CC+} | 22 V |
| V_{CC-} | -22 V |
| Differential input voltage (see Note 2) | ± 30 V |
| Input voltage range, V_I (any input) (see Note 1) | $V_{CC-} - 5$ V to V_{CC+} |
| Duration of short-circuit current at (or below) $T_A = 25^\circ\text{C}$ (see Note 3) | Unlimited |
| Continuous total power dissipation | See Dissipation Rating Table |
| Operating free-air temperature range, T_A : LT1014C, LT1014D | -0°C to 70°C |
| LT1014I, LT1014DI | -40°C to 105°C |
| LT1014M, LT1014AM, LT1014DM | -55°C to 125°C |
| Case temperature for 60 seconds: FK package | 260°C |
| Storage temperature range, T_{stg} | -65°C to 150°C |

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at the noninverting input with respect to the inverting input.
 3. The output may be shorted to either supply.

DISSIPATION RATING TABLE

| PACKAGE | $T_A \leq 25^\circ\text{C}$ POWER RATING | DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$ | $T_A = 70^\circ\text{C}$ POWER RATING | $T_A = 105^\circ\text{C}$ POWER RATING | $T_A = 125^\circ\text{C}$ POWER RATING |
|---------|---|---|--|---|---|
| DW | 1025 mW | 8.2 mW/ $^\circ\text{C}$ | 656 mW | 369 mW | 205 mW |
| FK | 1375 mW | 11.0 mW/ $^\circ\text{C}$ | 880 mW | 495 mW | 275 mW |
| J | 1375 mW | 11.0 mW/ $^\circ\text{C}$ | 880 mW | 495 mW | 275 mW |
| N | 1150 mW | 9.2 mW/ $^\circ\text{C}$ | 736 mW | 414 mW | 230 mW |



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A † | LT1014C | | | LT1014D | | | UNIT |
|--|--|------------|-------------|---------------|-------------|---------------|------------------------------|-----|------|
| | | | MIN | TYP‡ | MAX | MIN | TYP‡ | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$ | 25°C | 60 | 300 | 200 | 800 | μV | | |
| | | Full range | 550 | | | 1000 | | | |
| $\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage | | Full range | 0.4 | 2.5 | 0.7 | 5 | $\mu\text{V}/^\circ\text{C}$ | | |
| Long-term drift of input offset voltage | | 25°C | 0.5 | | | 0.5 | $\mu\text{V}/\text{mo}$ | | |
| I_{IO} Input offset current | | 25°C | 0.15 | 1.5 | 0.15 | 1.5 | nA | | |
| | | Full range | 2.8 | | | 2.8 | | | |
| I_{IB} Input bias current | | 25°C | -12 | -30 | -12 | -30 | nA | | |
| | | Full range | -38 | | | -38 | | | |
| V_{ICR} Common-mode input voltage range | | 25°C | -15 to 13.5 | -15.3 to 13.8 | -15 to 13.5 | -15.3 to 13.8 | V | | |
| | | Full range | -15 to 13 | | | -15 to 13 | | | |
| V_{OM} Maximum peak output voltage swing | $R_L = 2\ \text{k}\Omega$ | 25°C | ± 12.5 | ± 14 | ± 12.5 | ± 14 | V | | |
| | | Full range | ± 12 | | | ± 12 | | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = \pm 10\ \text{V}$, $R_L = 600\ \Omega$ | 25°C | 0.5 | 2 | 0.5 | 2 | $\text{V}/\mu\text{V}$ | | |
| | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 25°C | 1.2 | 8 | 1.2 | 8 | | | |
| | | Full range | 0.7 | | | 0.7 | | | |
| CMRR Common-mode rejection ratio | $V_{IC} = -15\ \text{V}$ to $13.5\ \text{V}$ | 25°C | 97 | 117 | 97 | 117 | dB | | |
| | $V_{IC} = -15\ \text{V}$ to $13\ \text{V}$ | Full range | 94 | | | 94 | | | |
| k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$) | $V_{CC\pm} = \pm 2\ \text{V}$ to $\pm 18\ \text{V}$ | 25°C | 100 | 117 | 100 | 117 | dB | | |
| | | Full range | 97 | | | 97 | | | |
| Channel separation | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 25°C | 120 | 137 | 120 | 137 | dB | | |
| r_{id} Differential input resistance | | 25°C | 70 | 300 | 70 | 300 | $\text{M}\Omega$ | | |
| r_{ic} Common-mode input resistance | | 25°C | 4 | | | 4 | $\text{G}\Omega$ | | |
| I_{CC} Supply current per amplifier | | 25°C | 0.35 | 0.55 | 0.35 | 0.55 | mA | | |
| | | Full range | 0.6 | | | 0.6 | | | |

† Full range is 0°C to 70°C.

‡ All typical values are at $T_A = 25^\circ\text{C}$.



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC\pm} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A^\dagger | LT1014C | | | LT1014D | | | UNIT |
|--|---|---------------|----------|-------------|------|----------|-------------|---------------|------------------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$ | 25°C | 90 | 450 | | 250 | 950 | μV | |
| | | Full range | | | 570 | | 1200 | | |
| I_{IO} Input offset current | | 25°C | 0.2 | 2 | | 0.2 | 2 | nA | |
| | | Full range | | | 6 | | 6 | | |
| I_{IB} Input bias current | | 25°C | -15 | -50 | | -15 | -50 | nA | |
| | | Full range | | | -90 | | -90 | | |
| V_{ICR} Common-mode input voltage range | | 25°C | 0 to 3.5 | -0.3 to 3.8 | | 0 to 3.5 | -0.3 to 3.8 | V | |
| | | Full range | 0 to 3 | | | 0 to 3 | | | |
| V_{OM} Maximum peak output voltage swing | Output low, No load | 25°C | 15 | 25 | | 15 | 25 | mV | |
| | Output low, $R_L = 600\ \Omega$ to GND | 25°C | 5 | 10 | | 5 | 10 | | |
| | | Full range | | | 13 | | 13 | | |
| | Output low, $I_{\text{sink}} = 1\text{ mA}$ | 25°C | 220 | 350 | | 220 | 350 | V | |
| | Output high, No load | 25°C | 4 | 4.4 | | 4 | 4.4 | | |
| | Output high, $R_L = 600\ \Omega$ to GND | 25°C | 3.4 | 4 | | 3.4 | 4 | | |
| Full range | | | | 3.2 | | 3.2 | | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = 5\text{ mV}$ to 4 V, $R_L = 500\ \Omega$ | 25°C | 1 | | | 1 | | | V/ μV |
| I_{CC} Supply current per amplifier | | 25°C | 0.3 | 0.5 | | 0.3 | 0.5 | mA | |
| | | Full range | | | 0.55 | | 0.55 | | |

† Full range is 0°C to 70°C.

operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---------------------|-----|------|-----|------------------------|
| SR Slew rate | | 0.2 | 0.4 | | V/ μs |
| V_n Equivalent input noise voltage | f = 10 Hz | | 24 | | nV/ $\sqrt{\text{Hz}}$ |
| | f = 1 kHz | | 22 | | |
| $V_{N(PP)}$ Peak-to-peak equivalent input noise voltage | f = 0.1 Hz to 10 Hz | | 0.55 | | μV |
| I_n Equivalent input noise current | f = 10 Hz | | 0.07 | | pA/ $\sqrt{\text{Hz}}$ |



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A † | LT1014I | | LT1014DI | | UNIT |
|--|--|------------|-------------|---------------|-------------|---------------|------------------------------|
| | | | MIN | TYP‡ | MAX | MIN | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$ | 25°C | 60 | 300 | 200 | 800 | μV |
| | | Full range | 550 | | 1000 | | |
| $\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage | | Full range | 0.4 | 2.5 | 0.7 | 5 | $\mu\text{V}/^\circ\text{C}$ |
| Long-term drift of input offset voltage | | 25°C | 0.5 | | 0.5 | | $\mu\text{V}/\text{mo}$ |
| I_{IO} Input offset current | | 25°C | 0.15 | 1.5 | 0.15 | 1.5 | nA |
| | | Full range | 2.8 | | 2.8 | | |
| I_{IB} Input bias current | | 25°C | -12 | -30 | -12 | -30 | nA |
| | | Full range | -38 | | -38 | | |
| V_{ICR} Common-mode input voltage range | | 25°C | -15 to 13.5 | -15.3 to 13.8 | -15 to 13.5 | -15.3 to 13.8 | V |
| | | Full range | -15 to 13 | | -15 to 13 | | |
| V_{OM} Maximum peak output voltage swing | $R_L = 2\ \text{k}\Omega$ | 25°C | ± 12.5 | ± 14 | ± 12.5 | ± 14 | V |
| | | Full range | ± 12 | | ± 12 | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = \pm 10\ \text{V}$, $R_L = 600\ \Omega$ | 25°C | 0.5 | 2 | 0.5 | 2 | $\text{V}/\mu\text{V}$ |
| | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 25°C | 1.2 | 8 | 1.2 | 8 | |
| | | Full range | 0.7 | | 0.7 | | |
| CMRR Common-mode rejection ratio | $V_{IC} = -15\ \text{V}$ to $13.5\ \text{V}$ | 25°C | 97 | 117 | 97 | 117 | dB |
| | | Full range | 94 | | 94 | | |
| k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$) | $V_{CC\pm} = \pm 2\ \text{V}$ to $\pm 18\ \text{V}$ | 25°C | 100 | 117 | 100 | 117 | dB |
| | | Full range | 97 | | 97 | | |
| Channel separation | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 25°C | 120 | 137 | 120 | 137 | dB |
| r_{id} Differential input resistance | | 25°C | 70 | 300 | 70 | 300 | $\text{M}\Omega$ |
| r_{ic} Common-mode input resistance | | 25°C | 4 | | 4 | | $\text{G}\Omega$ |
| I_{CC} Supply current per amplifier | | 25°C | 0.35 | 0.55 | 0.35 | 0.55 | mA |
| | | Full range | 0.6 | | 0.6 | | |

† Full range is -40°C to 105°C .

‡ All typical values are at $T_A = 25^\circ\text{C}$.



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A † | LT1014I | | | LT1014DI | | | UNIT |
|--|---|------------|----------|-------------|------|----------|------------------------|---------------|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$ | 25°C | 90 | 450 | | 250 | 950 | μV | |
| | | Full range | | | 570 | | 1200 | | |
| I_{IO} Input offset current | | 25°C | 0.2 | 2 | | 0.2 | 2 | nA | |
| | | Full range | | | 6 | | 6 | | |
| I_{IB} Input bias current | | 25°C | -15 | -50 | | -15 | -50 | nA | |
| | | Full range | | | -90 | | -90 | | |
| V_{ICR} Common-mode input voltage range | | 25°C | 0 to 3.5 | -0.3 to 3.8 | | 0 to 3.5 | -0.3 to 3.8 | V | |
| | | Full range | 0 to 3 | | | 0 to 3 | | | |
| V_{OM} Maximum peak output voltage swing | Output low, No load | 25°C | 15 | 25 | | 15 | 25 | mV | |
| | Output low, $R_L = 600\ \Omega$ to GND | 25°C | 5 | 10 | | 5 | 10 | | |
| | | Full range | | | 13 | | 13 | | |
| | Output low, $I_{\text{sink}} = 1\text{ mA}$ | 25°C | 220 | 350 | | 220 | 350 | V | |
| | Output high, No load | 25°C | 4 | 4.4 | | 4 | 4.4 | | |
| | Output high, $R_L = 600\ \Omega$ to GND | 25°C | 3.4 | 4 | | 3.4 | 4 | | |
| Full range | | | | 3.2 | | 3.2 | | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = 5\text{ mV}$ to 4 V , $R_L = 500\ \Omega$ | 25°C | 1 | | | 1 | $\text{V}/\mu\text{V}$ | | |
| I_{CC} Supply current per amplifier | | 25°C | 0.3 | 0.5 | | 0.3 | 0.5 | mA | |
| | | Full range | | | 0.55 | | 0.55 | | |

† Full range is -40°C to 105°C .

operating characteristics, $V_{CC+} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---------------------------------------|-----|------|-----|------------------------------|
| SR Slew rate | | 0.2 | 0.4 | | $\text{V}/\mu\text{s}$ |
| V_n Equivalent input noise voltage | $f = 10\text{ Hz}$ | | 24 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| | $f = 1\text{ kHz}$ | | 22 | | |
| $V_{N(PP)}$ Peak-to-peak equivalent input noise voltage | $f = 0.1\text{ Hz}$ to 10 Hz | | 0.55 | | μV |
| I_n Equivalent input noise current | $f = 10\text{ Hz}$ | | 0.07 | | $\text{pA}/\sqrt{\text{Hz}}$ |



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A^\dagger | LT1014M | | | LT1014AM | | | LT1014DM | | | UNIT |
|--|---|---------------|---|-----------------|------|-------------|-----------------|-----|-------------|-----------------|------------------------------|------|
| | | | MIN | TYP ‡ | MAX | MIN | TYP ‡ | MAX | MIN | TYP ‡ | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$ | 25°C | 60 | 300 | | 60 | 180 | | 200 | 800 | μV | |
| | | Full range | | | 550 | | 350 | | | 1000 | | |
| $\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage | | Full range | 0.5 | 2.5 | | 0.5 | 2 | | 0.5 | 2.5 | $\mu\text{V}/^\circ\text{C}$ | |
| Long-term drift of input offset voltage | | 25°C | 0.5 | | | 0.5 | | | 0.5 | | $\mu\text{V}/\text{mo}$ | |
| I_{IO} Input offset current | | 25°C | 0.15 | 1.5 | | 0.15 | 0.8 | | 0.15 | 1.5 | nA | |
| | | Full range | | | 5 | | 2.8 | | | 5 | | |
| I_{IB} Input bias current | | 25°C | -12 | -30 | | -12 | -20 | | -12 | -30 | nA | |
| | | Full range | | | -45 | | -30 | | | -45 | | |
| V_{ICR} Common-mode input voltage range | | 25°C | -15 to 13.5 | -15.3 to 13.8 | | -15 to 13.5 | -15.3 to 13.8 | | -15 to 13.5 | -15.3 to 13.8 | V | |
| | | Full range | -14.9 to 13 | | | -14.9 to 13 | | | -14.9 to 13 | | | |
| V_{OM} Maximum peak output voltage swing | $R_L = 2\ \text{k}\Omega$ | 25°C | ± 12.5 | ± 14 | | ± 13 | ± 14 | | ± 12.5 | ± 14 | V | |
| | | Full range | ± 11.5 | | | ± 12 | | | ± 11.5 | | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = \pm 10\ \text{V}$, $R_L = 600\ \Omega$ | 25°C | 0.5 | 2 | | 0.8 | 2.2 | | 0.5 | 2 | $\text{V}/\mu\text{V}$ | |
| | | 25°C | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 1.2 | 8 | | 1.5 | 8 | | 1.2 | | 8 |
| | | | | Full range | 0.25 | | | 0.4 | | | | 0.25 |
| CMRR Common-mode rejection ratio | $V_{IC} = -15\ \text{V}$ to 13.5 V | 25°C | 97 | 117 | | 100 | 117 | | 97 | 117 | dB | |
| | | Full range | 94 | | | 96 | | | 94 | | | |
| k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$) | $V_{CC\pm} = \pm 2\ \text{V}$ to $\pm 18\ \text{V}$ | 25°C | 100 | 117 | | 103 | 117 | | 100 | 117 | dB | |
| | | Full range | 97 | | | 100 | | | 97 | | | |
| Channel separation | $V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$ | 25°C | 120 | 137 | | 123 | 137 | | 120 | 137 | dB | |
| r_{id} Differential input resistance | | 25°C | 70 | 300 | | 100 | 300 | | 70 | 300 | $\text{M}\Omega$ | |
| r_{ic} Common-mode input resistance | | 25°C | 4 | | | 4 | | | 4 | | $\text{G}\Omega$ | |
| I_{CC} Supply current per amplifier | | 25°C | 0.35 | 0.55 | | 0.35 | 0.50 | | 0.35 | 0.55 | mA | |
| | | Full range | | | 0.7 | | 0.6 | | | 0.7 | | |

† Full range is -55°C to 125°C .

‡ All typical values are at $T_A = 25^\circ\text{C}$.



LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

electrical characteristics at specified free-air temperature, $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A^\dagger | LT1014M | | | LT1014AM | | | LT1014DM | | | UNIT |
|--|--|---------------|----------|-------------|-----|----------|-------------|-----|----------|-------------|------------------------|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\Omega$ | 25°C | 90 | 450 | | 90 | 280 | | 250 | 950 | μV | |
| | | Full range | 400 | 1500 | | 400 | 960 | | 800 | 2000 | | |
| | $R_S = 50\Omega$, $V_{IC} = 0.1\text{ V}$ | 125°C | 200 | 750 | | 200 | 480 | | 560 | 1200 | | |
| I_{IO} Input offset current | | 25°C | 0.2 | 2 | | 0.2 | 1.3 | | 0.2 | 2 | nA | |
| | | Full range | | 10 | | | 7 | | | 10 | | |
| I_{IB} Input bias current | | 25°C | -15 | -50 | | -15 | -35 | | -15 | -50 | nA | |
| | | Full range | | -120 | | | -90 | | | -120 | | |
| V_{ICR} Common-mode input voltage range | | 25°C | 0 to 3.5 | -0.3 to 3.8 | | 0 to 3.5 | -0.3 to 3.8 | | 0 to 3.5 | -0.3 to 3.8 | V | |
| | | Full range | 0.1 to 3 | | | 0.1 to 3 | | | 0.1 to 3 | | | |
| V_{OM} Maximum peak output voltage swing | Output low, No load | 25°C | 15 | 25 | | 15 | 25 | | 15 | 25 | mV | |
| | Output low, $R_L = 600\Omega$ to GND | 25°C | 5 | 10 | | 5 | 10 | | 5 | 10 | | |
| | | Full range | | 18 | | | 15 | | | 18 | | |
| | Output low, $I_{sink} = 1\text{ mA}$ | 25°C | 220 | 350 | | 220 | 350 | | 220 | 350 | V | |
| | Output high, No load | 25°C | 4 | 4.4 | | 4 | 4.4 | | 4 | 4.4 | | |
| | Output high, $R_L = 600\Omega$ to GND | Full range | 3.1 | | | 3.2 | | | 3.1 | | | |
| A_{VD} Large-signal differential voltage amplification | $V_O = 5\text{ mV}$ to 4 V, $R_L = 500\Omega$ | 25°C | | 1 | | | 1 | | | 1 | $\text{V}/\mu\text{V}$ | |
| I_{CC} Supply current per amplifier | | 25°C | 0.3 | 0.5 | | 0.3 | 0.45 | | 0.3 | 0.5 | mA | |
| | | Full range | | 0.65 | | | 0.55 | | | 0.65 | | |

† Full range is -55°C to 125°C.

operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|------------------------------|-----|------|-----|------------------------------|
| SR Slew rate | | 0.2 | 0.4 | | $\text{V}/\mu\text{s}$ |
| V_n Equivalent input noise voltage | $f = 10\text{ Hz}$ | | 24 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| | $f = 1\text{ kHz}$ | | 22 | | |
| $V_{N(PP)}$ Peak-to-peak equivalent input noise voltage | $f = 0.1\text{ Hz}$ to 10 Hz | | 0.55 | | μV |
| I_n Equivalent input noise current | $f = 10\text{ Hz}$ | | 0.07 | | $\text{pA}/\sqrt{\text{Hz}}$ |



TYPICAL CHARACTERISTICS

Table of Graphs

| | | FIGURE | |
|-----------------|--|--------------------|-------|
| V_{IO} | Input offset voltage vs Balanced source resistance | 1 | |
| V_{IO} | Input offset voltage vs Free-air temperature | 2 | |
| ΔV_{IO} | Warm-Up Change in input offset voltage vs Elapsed time | 3 | |
| I_{IO} | Input offset current vs Free-air temperature | 4 | |
| I_{IB} | Input bias current vs Free-air temperature | 5 | |
| V_{IC} | Common-mode input voltage vs Input bias current | 6 | |
| A_{VD} | Differential voltage amplification | vs Load resistance | 7, 8 |
| | | vs Frequency | 9, 10 |
| | Channel separation vs Frequency | 11 | |
| | Output saturation voltage vs Free-air temperature | 12 | |
| CMRR | Common-mode rejection ratio vs Frequency | 13 | |
| k_{SVR} | Supply-voltage rejection ratio vs Frequency | 14 | |
| I_{CC} | Supply current vs Free-air temperature | 15 | |
| I_{OS} | Short-circuit output current vs Elapsed time | 16 | |
| V_n | Equivalent input noise voltage vs Frequency | 17 | |
| I_n | Equivalent input noise current vs Frequency | 17 | |
| $V_{N(PP)}$ | Peak-to-peak input noise voltage vs Time | 18 | |
| | Pulse response (small signal) vs Time | 19, 21 | |
| | Pulse response (large signal) vs Time | 20, 22, 23 | |
| | Phase shift vs Frequency | 9 | |

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

TYPICAL CHARACTERISTICS†

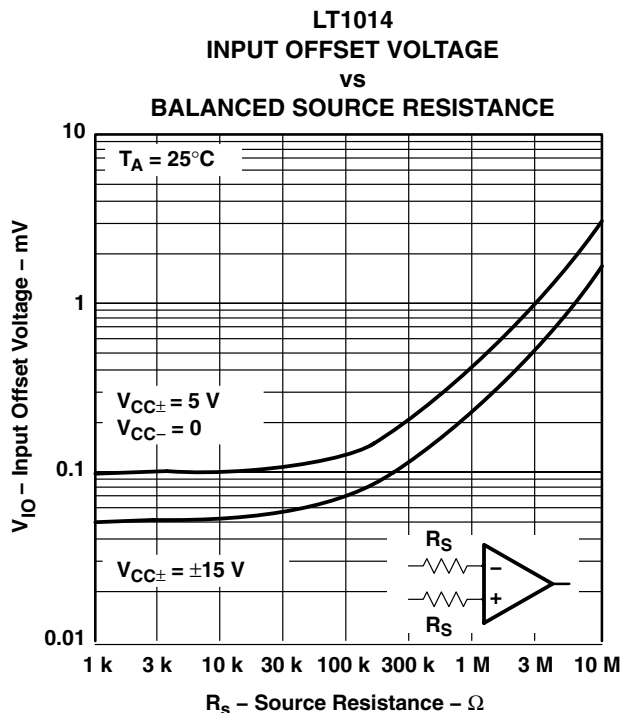


Figure 1

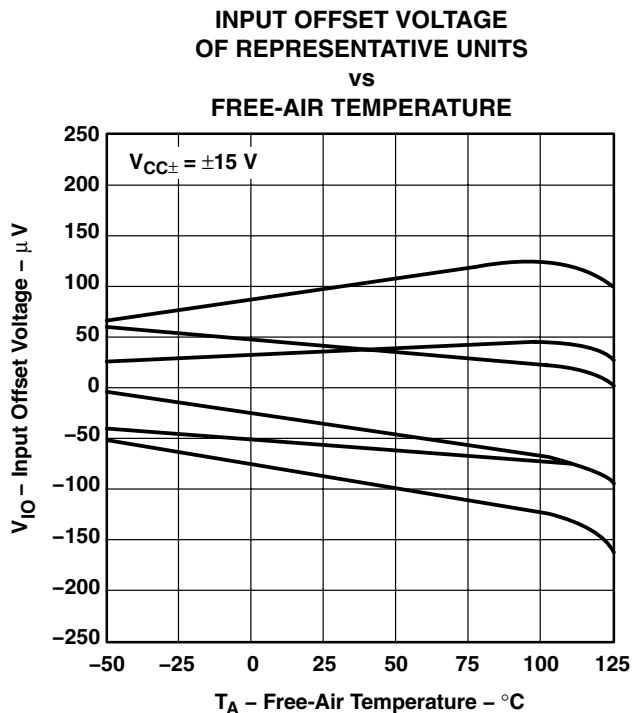


Figure 2

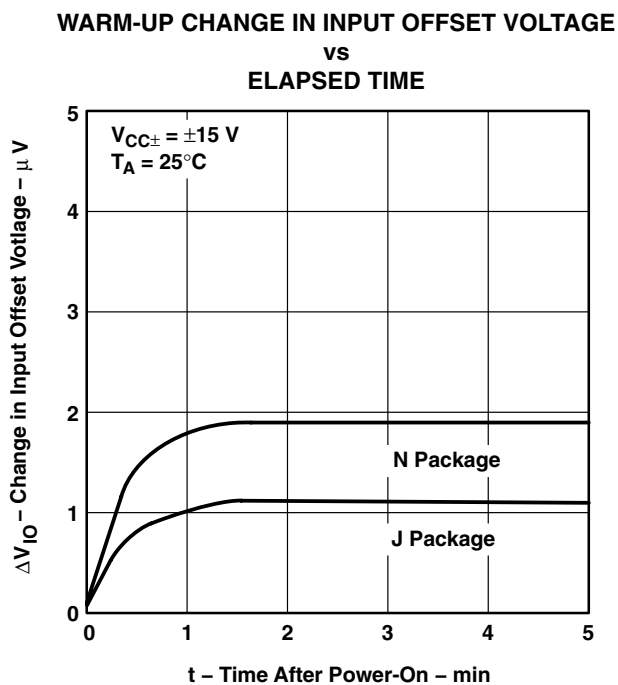


Figure 3

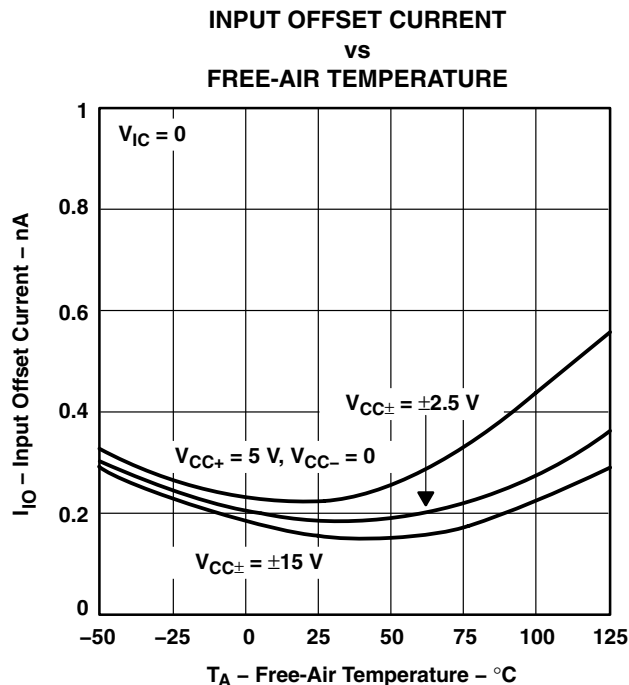
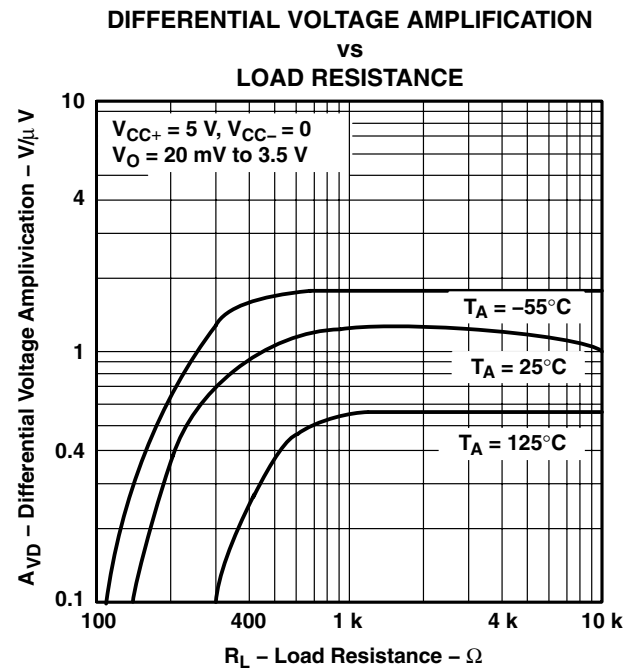
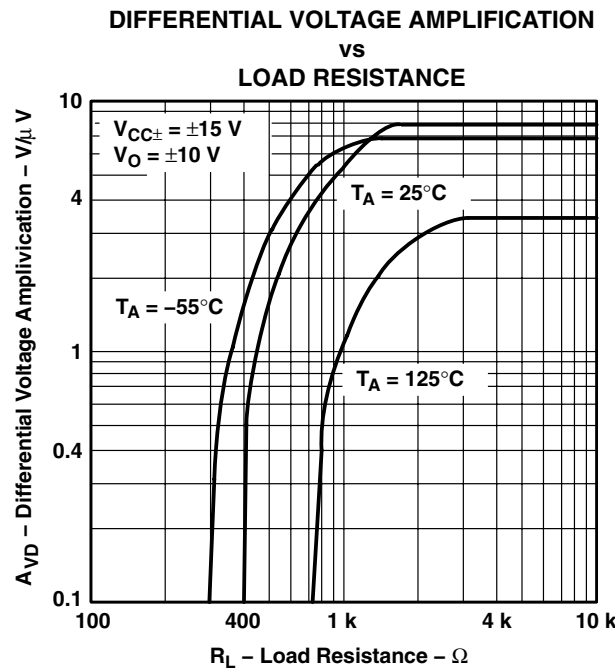


Figure 4

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

TYPICAL CHARACTERISTICS†

**DIFFERENTIAL VOLTAGE AMPLIFICATION
AND PHASE SHIFT
vs
FREQUENCY**

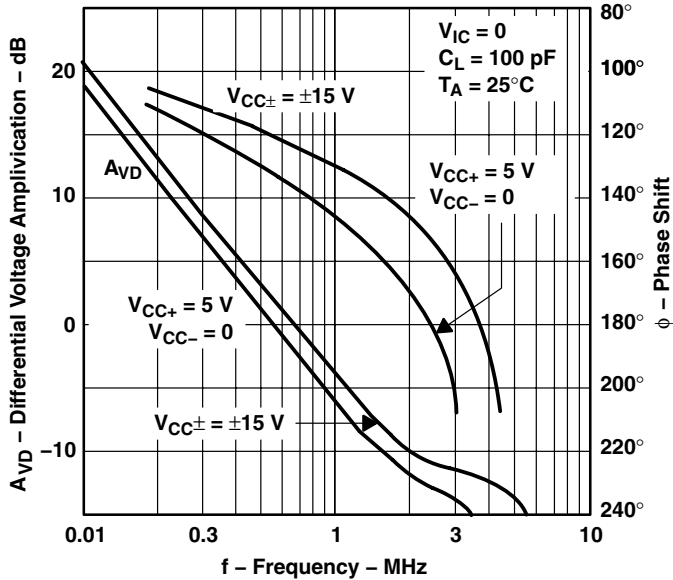


Figure 9

**DIFFERENTIAL VOLTAGE AMPLIFICATION
vs
FREQUENCY**

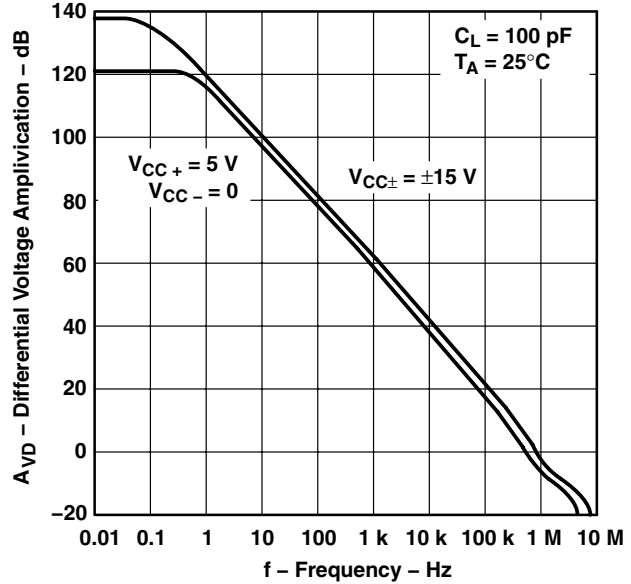


Figure 10

**CHANNEL SEPARATION
vs
FREQUENCY**



Figure 11

**OUTPUT SATURATION VOLTAGE
vs
FREE-AIR TEMPERATURE**

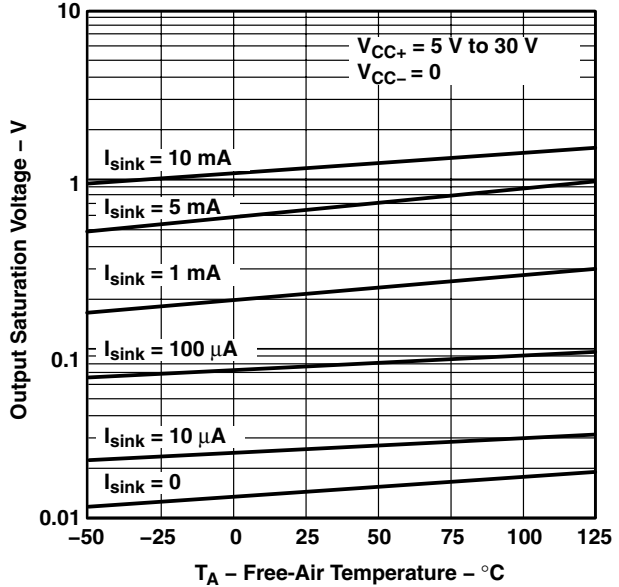


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

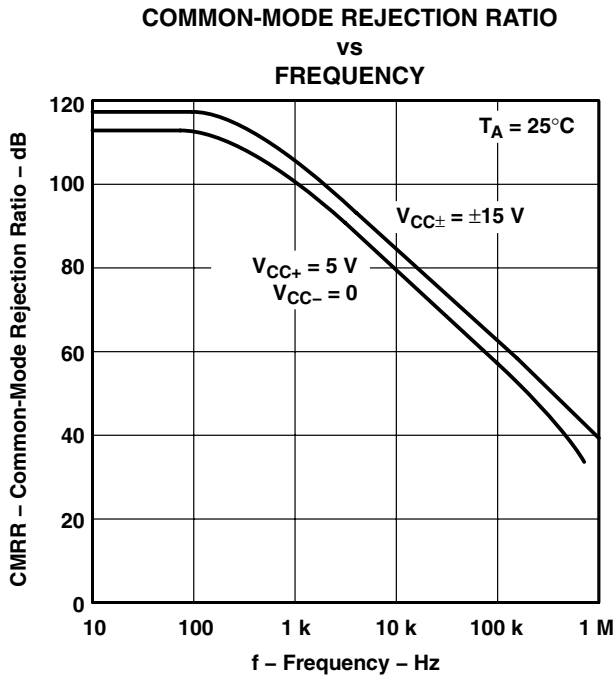


Figure 13

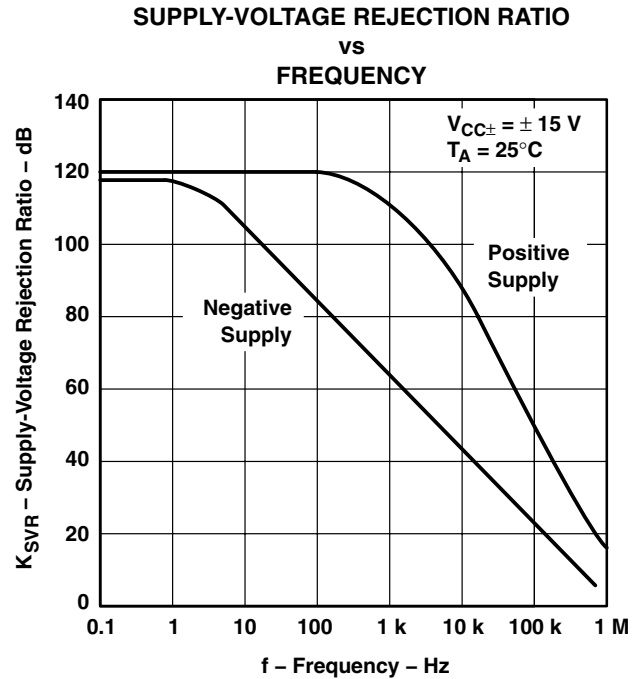


Figure 14

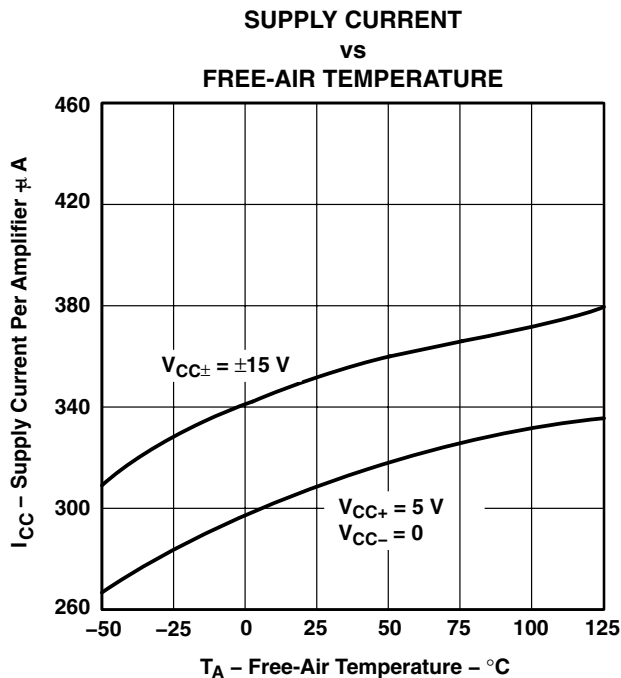


Figure 15

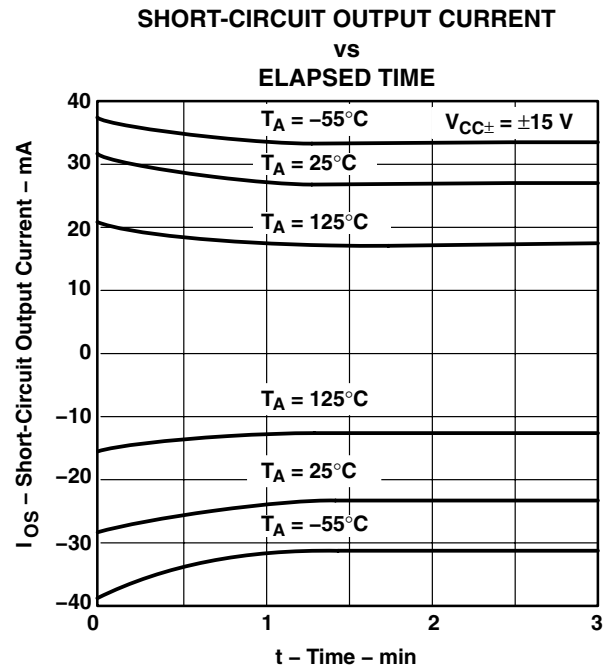


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

TYPICAL CHARACTERISTICS

**EQUIVALENT INPUT NOISE VOLTAGE
AND EQUIVALENT INPUT NOISE CURRENT**

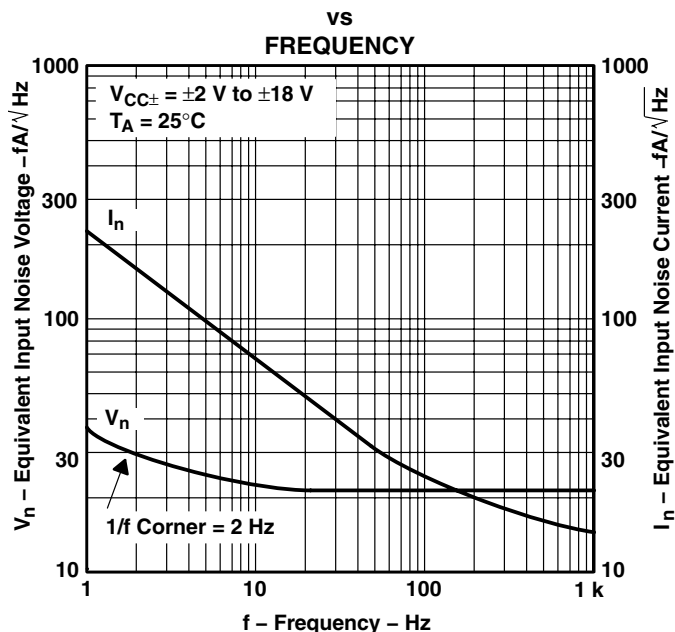


Figure 17

**PEAK-TO-PEAK INPUT NOISE VOLTAGE
OVER A 10-SECOND PERIOD**

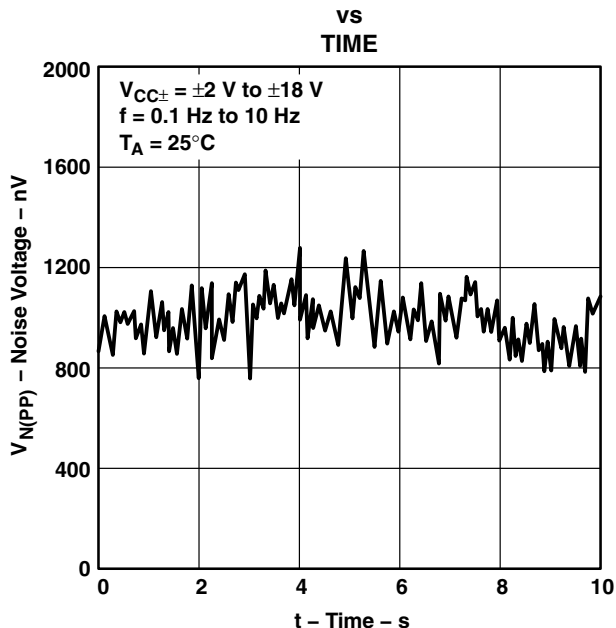


Figure 18

**VOLTAGE-FOLLOWER SMALL-SIGNAL
PULSE RESPONSE**

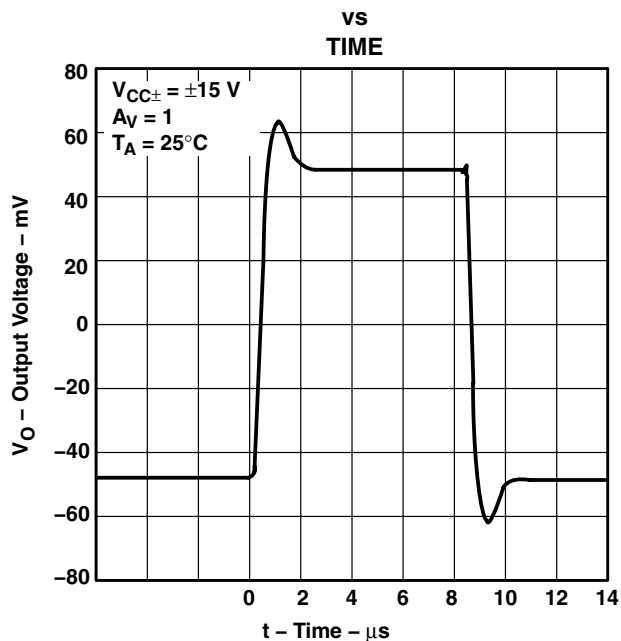


Figure 19

**VOLTAGE-FOLLOWER LARGE-SIGNAL
PULSE RESPONSE**

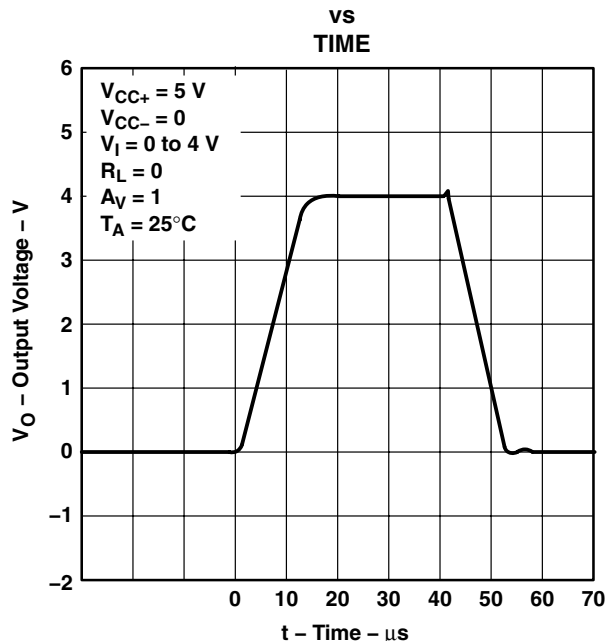


Figure 20



TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER SMALL-SIGNAL
 PULSE RESPONSE
 vs
 TIME

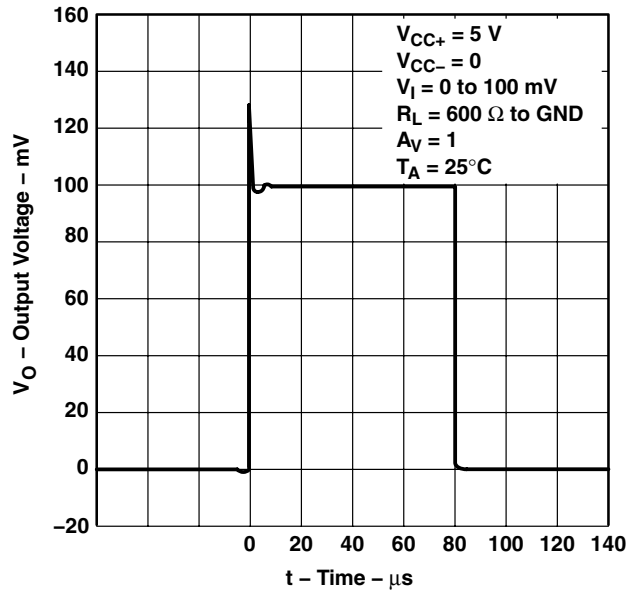


Figure 21

VOLTAGE-FOLLOWER LARGE-SIGNAL
 PULSE RESPONSE
 vs
 TIME

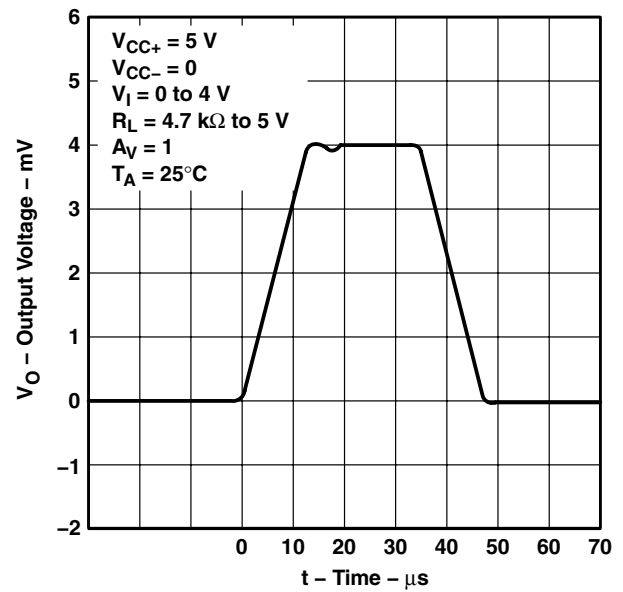


Figure 22

VOLTAGE-FOLLOWER LARGE-SIGNAL
 PULSE RESPONSE
 vs
 TIME

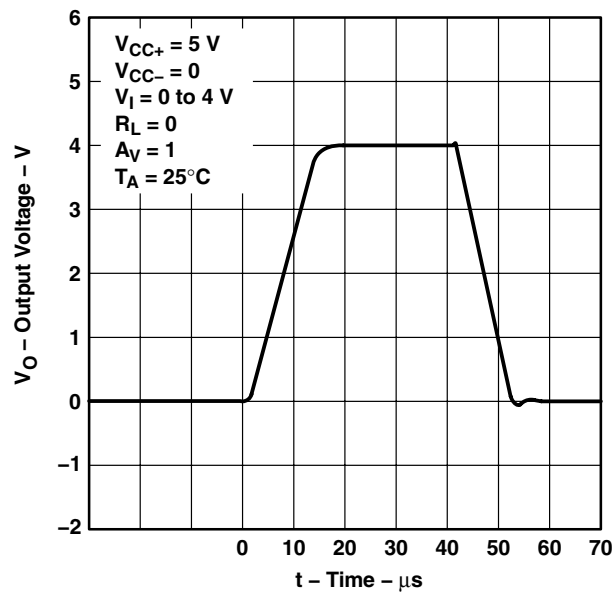


Figure 23

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039D – JULY 1989 – REVISED AUGUST 2009

APPLICATION INFORMATION

single-supply operation

The LT1014 is fully specified for single-supply operation ($V_{CC-} = 0$). The common-mode input voltage range includes ground, and the output swings within a few millivolts of ground.

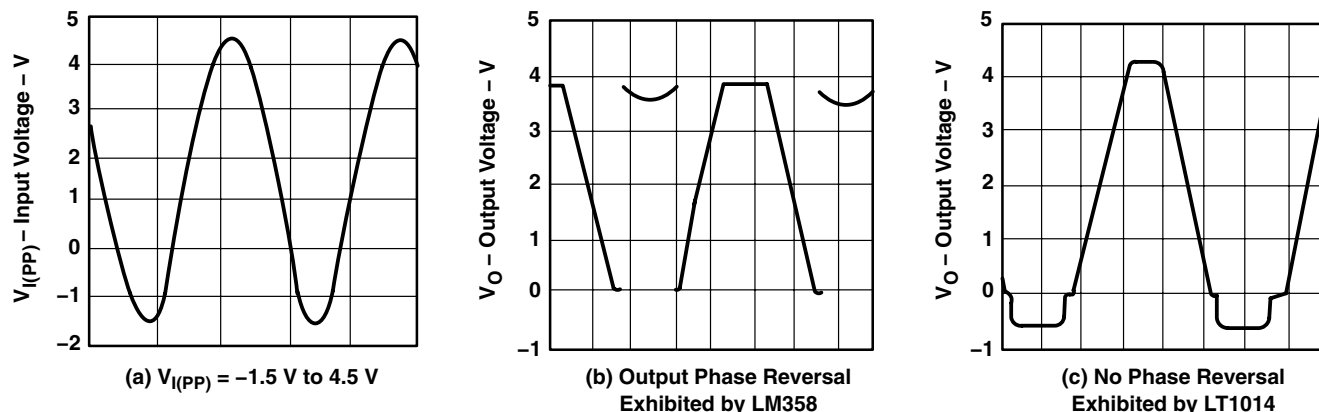
Furthermore, the LT1014 has specific circuitry that addresses the difficulties of single-supply operation, both at the input and at the output. At the input, the driving signal can fall below 0 V, either inadvertently or on a transient basis. If the input is more than a few hundred millivolts below ground, the LT1014 is designed to deal with the following two problems that can occur:

1. On many other operational amplifiers, when the input is more than a diode drop below ground, unlimited current flows from the substrate (V_{CC-} terminal) to the input, which can destroy the unit. On the LT1014, the 400- Ω resistors in series with the input (see schematic) protect the device even when the input is 5 V below ground.
2. When the input is more than 400 mV below ground (at $T_A = 25^\circ\text{C}$), the input stage of similar type operational amplifiers saturates, and phase reversal occurs at the output. This can cause lockup in servo systems. Because of unique phase-reversal protection circuitry (Q21, Q22, Q27, and Q28), the LT1014 outputs do not reverse, even when the inputs are at -1.5 V (see Figure 24).

However, this phase-reversal protection circuitry does not function when the other operational amplifier on the LT1014 is driven hard into negative saturation at the output. Phase-reversal protection does not work on an amplifier:

- When 4's output is in negative saturation (the outputs of 2 and 3 have no effect)
- When 3's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 2's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 1's output is in negative saturation (the outputs of 2 and 3 have no effect)

At the output, other single-supply designs either cannot swing to within 600 mV of ground or cannot sink more than a few microamperes while swinging to ground. The all-npn output stage of the LT1014 maintains its low output resistance and high gain characteristics until the output is saturated. In dual-supply operations, the output stage is free of crossover distortion.



**Figure 24. Voltage-Follower Response
With Input Exceeding the Negative Common-Mode Input Voltage Range**

APPLICATION INFORMATION

comparator applications

The single-supply operation of the LT1014 can be used as a precision comparator with TTL-compatible output. In systems using both operational amplifiers and comparators, the LT1014 can perform multiple duties (see Figures 25 and 26).



Figure 25. Low-to-High-Level Output Response for Various Input Overdrives

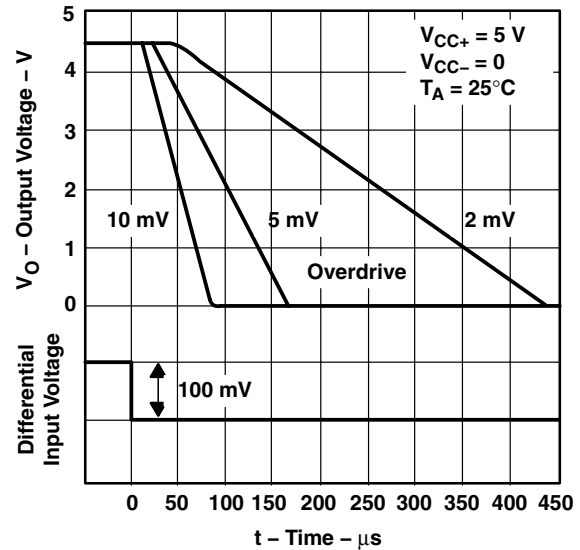


Figure 26. High-to-Low-Level Output Response for Various Input Overdrives

low-supply operation

The minimum supply voltage for proper operation of the LT1014 is 3.4 V (three Ni-Cad batteries). Typical supply current at this voltage is 290 μ A; therefore, power dissipation is only 1 mW per amplifier.

offset voltage and noise testing

Figure 30 shows the test circuit for measuring input offset voltage and its temperature coefficient. This circuit with supply voltages increased to ± 20 V is also used as the burn-in configuration.

The peak-to-peak equivalent input noise voltage of the LT1014 is measured using the test circuit shown in Figure 27. The frequency response of the noise tester indicates that the 0.1-Hz corner is defined by only one zero. The test time to measure 0.1-Hz to 10-Hz noise should not exceed 10 seconds, as this time limit acts as an additional zero to eliminate noise contribution from the frequency band below 0.1 Hz.

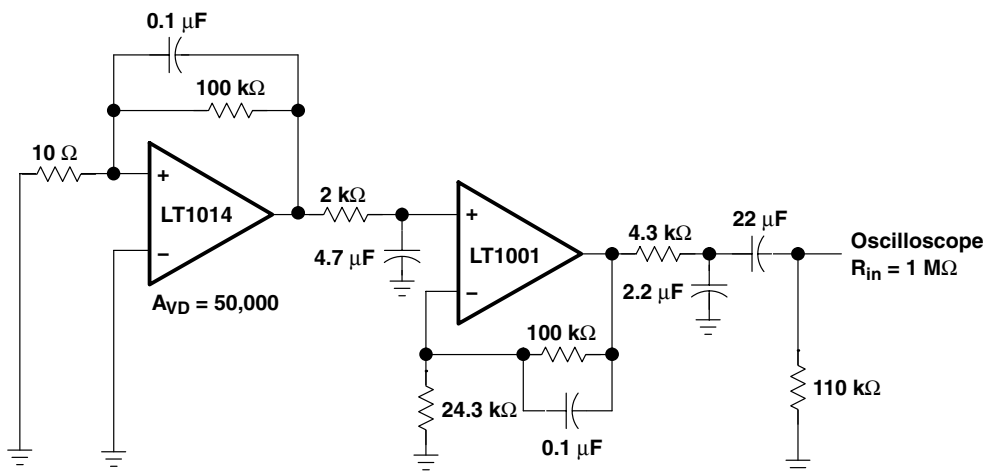
An input noise-voltage test is recommended when measuring the noise of a large number of units. A 10-Hz input noise-voltage measurement correlates well with a 0.1-Hz peak-to-peak noise reading because both results are determined by the white noise and the location of the 1/f corner frequency.

Noise current is measured by the circuit and formula shown in Figure 28. The noise of the source resistors is subtracted.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

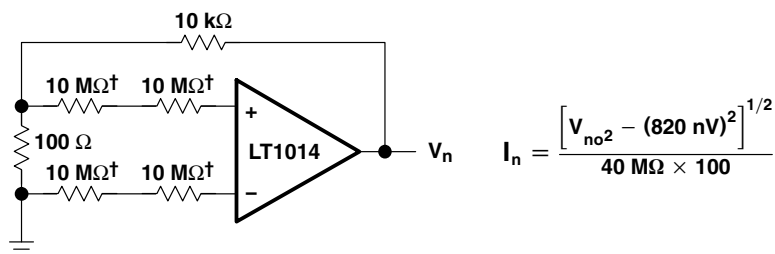
SLOS039D – JULY 1989 – REVISED AUGUST 2009

APPLICATION INFORMATION



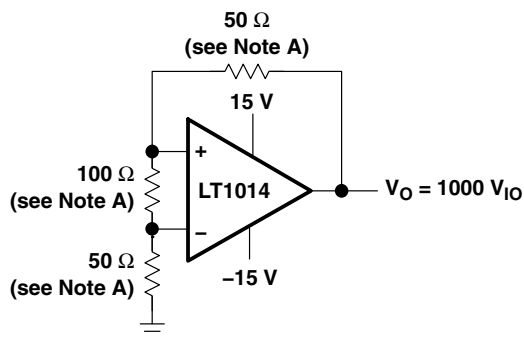
NOTE A: All capacitor values are for nonpolarized capacitors only.

Figure 27. 0.1-Hz to 10-Hz Peak-to-Peak Noise Test Circuit



† Metal-film resistor

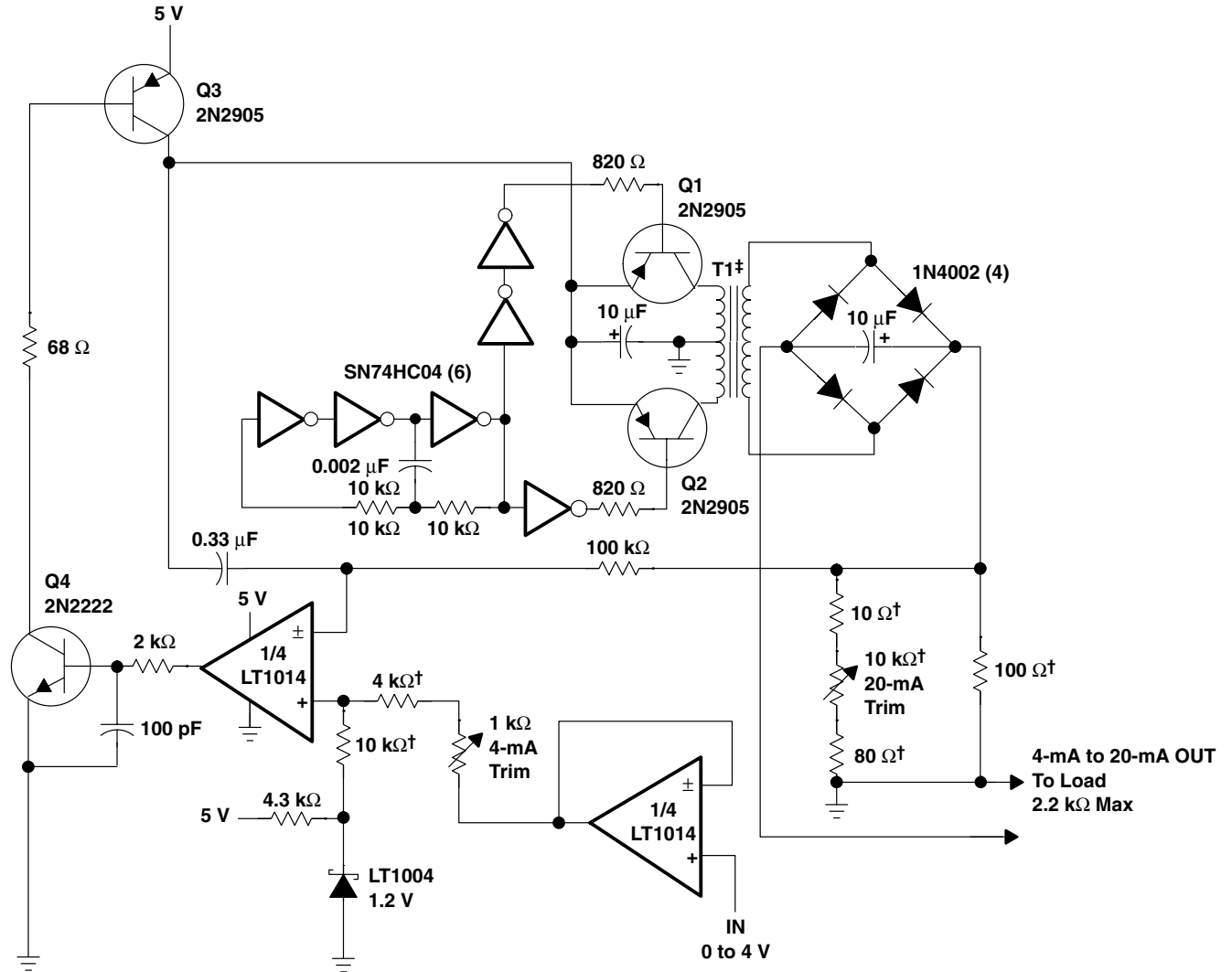
Figure 28. Noise-Current Test Circuit and Formula



NOTE A: Resistors must have low thermoelectric potential.

Figure 29. Test Circuit for V_{IO} and αV_{IO}

APPLICATION INFORMATION



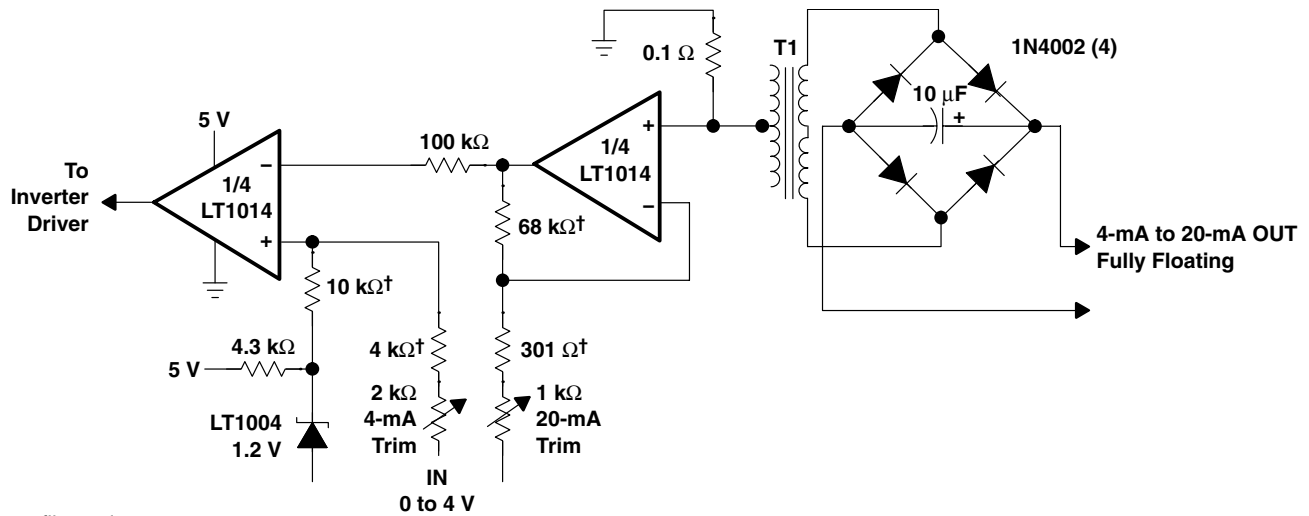
† 1% film resistor. Match 10-kΩ resistors 0.05%.
 ‡ T1 = PICO-31080

Figure 30. 5-V Powered, 4-mA to 20-mA Current-Loop Transmitter With 12-Bit Accuracy

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

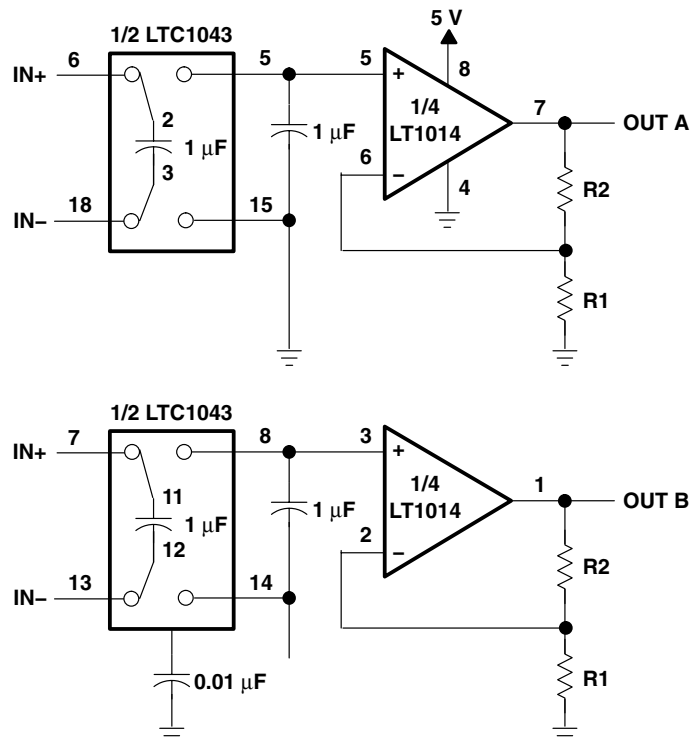
SLOS039D – JULY 1989 – REVISED AUGUST 2009

APPLICATION INFORMATION



† 1% film resistor

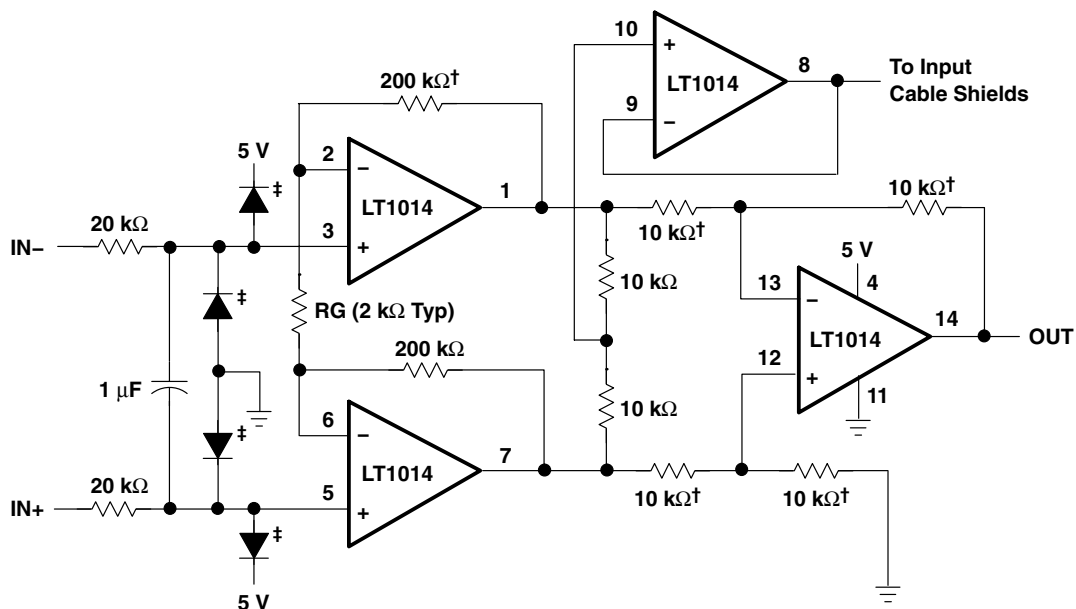
Figure 31. Fully Floating Modification to 4-mA to 20-mA Current-Loop Transmitter With 8-Bit Accuracy



NOTE A: $V_{IO} = 150 \mu\text{V}$, $A_{VD} = (R1/R2) + 1$, $\text{CMRR} = 120 \text{ dB}$, $V_{ICR} = 0 \text{ to } 5 \text{ V}$

Figure 32. 5-V Single-Supply Dual Instrumentation Amplifier

APPLICATION INFORMATION



† † 1% film resistor. Match 10-kΩ resistors 0.05%.

‡ For high source impedances, use 2N2222 as diodes (with collector connected to base).

NOTE A: $A_{VD} = (400,000/RG) + 1$

Figure 33. 5-V Powered Precision Instrumentation Amplifier

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| 5962-89677012A | ACTIVE | LCCC | FK | 20 | 1 | TBD | Call TI | Call TI | |
| 5962-8967701CA | ACTIVE | CDIP | J | 14 | 1 | TBD | Call TI | Call TI | |
| 5962-89677022A | ACTIVE | LCCC | FK | 20 | 1 | TBD | Call TI | Call TI | |
| 5962-8967702CA | ACTIVE | CDIP | J | 14 | 1 | TBD | Call TI | Call TI | |
| LT1014AMFKB | ACTIVE | LCCC | FK | 20 | 1 | TBD | POST-PLATE | N / A for Pkg Type | |
| LT1014AMJ | ACTIVE | CDIP | J | 14 | 1 | TBD | A42 | N / A for Pkg Type | |
| LT1014AMJB | ACTIVE | CDIP | J | 14 | 1 | TBD | A42 | N / A for Pkg Type | |
| LT1014CN | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| LT1014CNE4 | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| LT1014DDW | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DDWE4 | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DDWG4 | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DDWR | ACTIVE | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DDWRE4 | ACTIVE | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DDWRG4 | ACTIVE | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DIDW | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DIDWG4 | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DIDWR | ACTIVE | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DIDWRG4 | ACTIVE | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DIN | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| LT1014DINE4 | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|----------------------|------------------------------|-----------------------------|
| LT1014DMDW | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DMDWG4 | ACTIVE | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| LT1014DN | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| LT1014DNE4 | ACTIVE | PDIP | N | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| LT1014IN | OBSOLETE | PDIP | N | 14 | | TBD | Call TI | Call TI | |
| LT1014MFKB | ACTIVE | LCCC | FK | 20 | 1 | TBD | POST-PLATE | N / A for Pkg Type | |
| LT1014MJ | ACTIVE | CDIP | J | 14 | 1 | TBD | A42 | N / A for Pkg Type | |
| LT1014MJB | ACTIVE | CDIP | J | 14 | 1 | TBD | A42 | N / A for Pkg Type | |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LT1014D :

- Enhanced Product: [LT1014D-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LT1014DDWR | SOIC | DW | 16 | 2000 | 330.0 | 16.4 | 10.75 | 10.7 | 2.7 | 12.0 | 16.0 | Q1 |
| LT1014DIDWR | SOIC | DW | 16 | 2000 | 330.0 | 16.4 | 10.75 | 10.7 | 2.7 | 12.0 | 16.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LT1014DDWR | SOIC | DW | 16 | 2000 | 367.0 | 367.0 | 38.0 |
| LT1014DIDWR | SOIC | DW | 16 | 2000 | 367.0 | 367.0 | 38.0 |

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



| DIM \ PINS ** | 14 | 16 | 18 | 20 |
|---------------|------------------------|------------------------|------------------------|------------------------|
| A | 0.300 (7,62) BSC | 0.300 (7,62) BSC | 0.300 (7,62) BSC | 0.300 (7,62) BSC |
| B MAX | 0.785 (19,94) | .840 (21,34) | 0.960 (24,38) | 1.060 (26,92) |
| B MIN | — | — | — | — |
| C MAX | 0.300 (7,62) | 0.300 (7,62) | 0.310 (7,87) | 0.300 (7,62) |
| C MIN | 0.245 (6,22) | 0.245 (6,22) | 0.220 (5,59) | 0.245 (6,22) |



4040083/F 03/03

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package is hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



| NO. OF TERMINALS ** | A | | B | |
|---------------------|------------------|------------------|------------------|------------------|
| | MIN | MAX | MIN | MAX |
| 20 | 0.342 (8,69) | 0.358 (9,09) | 0.307 (7,80) | 0.358 (9,09) |
| 28 | 0.442 (11,23) | 0.458 (11,63) | 0.406 (10,31) | 0.458 (11,63) |
| 44 | 0.640 (16,26) | 0.660 (16,76) | 0.495 (12,58) | 0.560 (14,22) |
| 52 | 0.740 (18,78) | 0.761 (19,32) | 0.495 (12,58) | 0.560 (14,22) |
| 68 | 0.938 (23,83) | 0.962 (24,43) | 0.850 (21,6) | 0.858 (21,8) |
| 84 | 1.141 (28,99) | 1.165 (29,59) | 1.047 (26,6) | 1.063 (27,0) |



4040140/D 01/11

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a metal lid.
 - Falls within JEDEC MS-004

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AA.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

| | |
|------------------------------|--|
| Audio | www.ti.com/audio |
| Amplifiers | amplifier.ti.com |
| Data Converters | dataconverter.ti.com |
| DLP® Products | www.dlp.com |
| DSP | dsp.ti.com |
| Clocks and Timers | www.ti.com/clocks |
| Interface | interface.ti.com |
| Logic | logic.ti.com |
| Power Mgmt | power.ti.com |
| Microcontrollers | microcontroller.ti.com |
| RFID | www.ti-rfid.com |
| OMAP Applications Processors | www.ti.com/omap |
| Wireless Connectivity | www.ti.com/wirelessconnectivity |

Applications

| | |
|-------------------------------|--|
| Automotive and Transportation | www.ti.com/automotive |
| Communications and Telecom | www.ti.com/communications |
| Computers and Peripherals | www.ti.com/computers |
| Consumer Electronics | www.ti.com/consumer-apps |
| Energy and Lighting | www.ti.com/energy |
| Industrial | www.ti.com/industrial |
| Medical | www.ti.com/medical |
| Security | www.ti.com/security |
| Space, Avionics and Defense | www.ti.com/space-avionics-defense |
| Video and Imaging | www.ti.com/video |

TI E2E Community

e2e.ti.com